

isc Silicon NPN Darlington Power Transistor

BDW83D

DESCRIPTION

- Collector Current $I_C = 15A$
- High DC Current Gain $h_{FE} = 750(\text{Min}) @ I_C = 6A$
- Complement to Type BDW84D
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

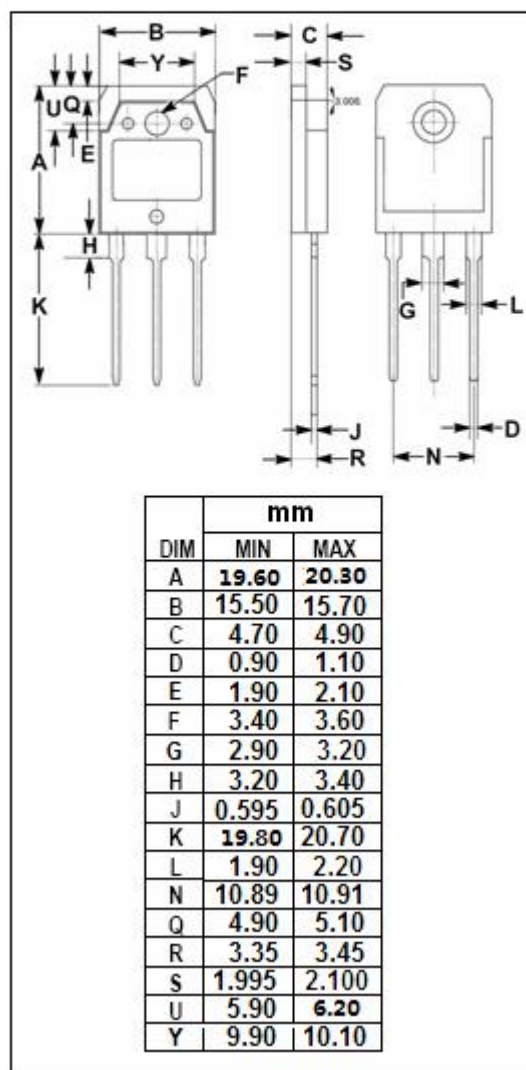
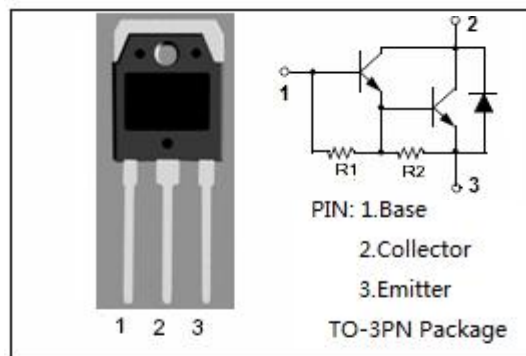
- Designed for general purpose amplifier and low speed switching applications

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CER}	Collector-Emitter Voltage	120	V
V_{CEO}	Collector-Emitter Voltage	120	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	15	A
I_B	Base Current-Continuous	0.5	A
P_C	Collector Power Dissipation @ $T_a = 25^\circ\text{C}$	3.5	W
	Collector Power Dissipation @ $T_c = 25^\circ\text{C}$	150	
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-65~150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	0.83	$^\circ\text{C/W}$
$R_{th\ j-a}$	Thermal Resistance, Junction to Ambient	35.7	$^\circ\text{C/W}$



isc Silicon NPN Darlington Power Transistor**BDW83D****ELECTRICAL CHARACTERISTICS****T_C=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 30mA ; I _B =0	120			V
V _{CE(sat)-1}	Collector-Emitter Saturation Voltage	I _C = 6A; I _B = 12mA			2.5	V
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = 15A; I _B = 150mA			4.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 6A ; V _{CE} = 3V			2.5	V
I _{CEO}	Collector Cutoff Current	V _{CE} = 60V; I _B = 0			1.0	mA
I _{CBO}	Collector Cutoff Current	V _{CB} = 120V; I _E = 0 V _{CB} = 120V; I _E = 0; T _C = 150°C			0.5 5.0	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C =0			2.0	mA
h _{FE-1}	DC Current Gain	I _C = 6A ; V _{CE} = 3V	750		20000	
h _{FE-2}	DC Current Gain	I _C = 15A ; V _{CE} = 3V	100			

Switching times

t _{on}	Turn-on Time	I _C = 10A; I _{B1} = -I _{B2} = 40mA; R _L = 3 Ω ; V _{BE(OFF)} = -4.2V		0.9		μ s
t _{off}	Turn-off Time			7.0		μ s

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